

# 4 $\Omega,$ 360 MHz, Dual SPST Analog Switches

### DESCRIPTION

The DG3537, DG3538, DG3539, DG3540 are dual SPST analog switches which operate from 1.8 V to 5.5 V single rail power supply. They are design for audio, video, and USB switching applications.

The devices have 4  $\Omega$  on-resistance and 360 MHz 3 dB bandwidth. 0.2  $\Omega$  on-resistance matching and 1  $\Omega$  flatness make the device high linearity. The devices are 1.6 V logic compatible within the full operation voltage range.

These switches are built on a sub-micron high density process that brings low power consumption and low voltage performance.

The switches are packaged in MICRO FOOT chip scale package of  $3 \times 3$  bump array.

As a committed partner to the community and environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For MICRO FOOT analog switch products manufactured with tin/silver/copper (SnAgCu) device termination, the lead (Pb)-free "-E1" suffix is being used as a designator.

#### FEATURES

- 1.8 V to 5.5 V operation
- 3 Ω at 2.7 V R<sub>ON</sub>
- 360 MHz 3 dB bandwidth
- ESD method 3015.7 > 2 kV
- Latch-up current 0.300 mA (JESD 78)
- 1.6 V logic compatible

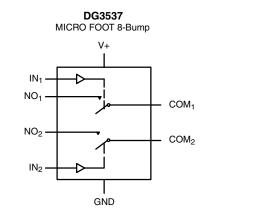
#### BENEFITS

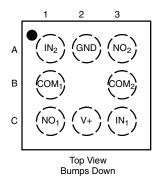
- Space saving MICRO FOOT<sup>®</sup> package
- High linearity
- Low power consumption
- High bandwidth
- Full rail Signal swing range

#### **APPLICATIONS**

- · Cellular phones
- MP3
  - Media players
  - Modems
  - Hard drives
  - PCMCIA

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





**Device Marking** 



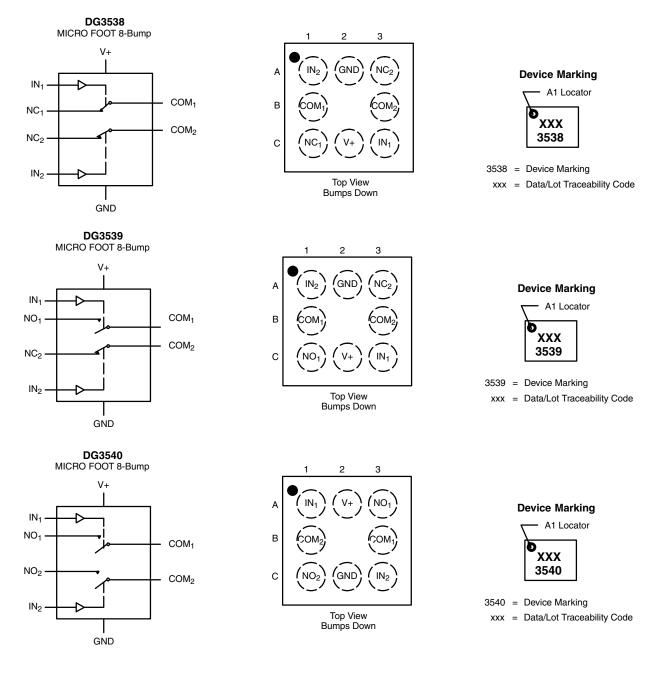
3537 = Device Marking xxx = Data/Lot Traceability Code

Document Number: 73320 S11-0303-Rev. D, 28-Feb-11





## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE					
Logic	NC1 and NC2	NO1 and NO2			
0	ON	OFF			
1	OFF	ON			

ORDERING INFORMATION						
Temp. Range	Package	Part Number				
- 40 °C to 85 °C	MICRO FOOT: 8 Bump (3 x 3, 0.5 mm Pitch, 238 µm Bump Height)	DG35337DB-T5-E1 DG3538DB-T5-E1 DG3539DB-T5-E1 DG3540DB-T1-E1				

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ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Reference V+ to GND		- 0.3 to + 6	N/			
IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3 V)	V			
Continuous Current (NO, NC, COM)		± 100	mA			
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 200	mA			
Storage Temperature	(D Suffix)	- 65 to 150	**			
Package Solder Reflow Conditions <sup>b</sup>	IR/Convection	250	°C			
ESD per Method 3015.7	·	> 2	kV			
Power Dissipation (Packages) <sup>c</sup>	MICRO FOOT: 8 Bump (3 x 3 mm) <sup>d</sup>	400	mW			

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. Refer to IPC/JEDEC (J-STD-020B)

c. All bumps welded or soldered to PC Board.

d. Derate 5.0 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS (V+	= 3 V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 2.7 to 3.6 V, $V_{IN}$ = 0.5 V or 1.4 V <sup>e</sup>	Temp. <sup>a</sup>	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
Analog Switch			•	•			
Analog Signal Range <sup>d</sup>	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		Full	0		V+	v
On-Resistance <sup>d</sup>	R <sub>ON</sub>		Room Full		3	4 4.3	
R <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	$V$ + = 2.7 V, $V_{COM}$ = 0.2/1.5 V I <sub>NO</sub> , I <sub>NC</sub> = 10 mA	Room		0.75	1.2	Ω
On-Resistance Match Between Channels <sup>d</sup>	$\Delta R_{DS(on)}$		Room			0.25	
Switch Off Lookoga Currant	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 3.6 V,	Room Full	- 2 - 20		2 20	
Switch Off Leakage Current <sup>r</sup>	I <sub>COM(off)</sub>	$V_{NO}$ , $V_{NC}$ = 0.3 V/3.3 V, $V_{COM}$ = 3.3 V/0.3 V	Room Full	- 2 - 20		2 20	nA
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	V+ = 3.6 V, V <sub>NO</sub> , V <sub>NC</sub> = V <sub>COM</sub> = 0.3 V/3.3 V	Room Full	- 2 - 20		2 20	
Digital Control			•	•			
Input High Voltage <sup>d</sup>	V <sub>INH</sub>		Full	1.4			v
Input Low Voltage	V <sub>INL</sub>		Full			0.5	v
Input Capacitance	C <sub>in</sub>		Full		8		pF
Input Current <sup>f</sup>	$I_{\rm INL}$ or $I_{\rm INH}$	V <sub>IN</sub> = 0 or V+	Full	1		1	μΑ

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SPECIFICATIONS (V+	= 3 V)						
		Test Conditions Otherwise Unless Specified		- 40	Limits ) °C to 85	5 °C	
Parameter	Symbol	V+ = 2.7 to 3.6 V, $V_{\text{IN}}$ = 0.5 V or 1.4 $\text{V}^{\text{e}}$	Temp. <sup>a</sup>	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	V+ = 2.7 V, V <sub>NO</sub> or V <sub>NC</sub> = 1.5 V	Room Full		16	46 48	ns
Turn-Off Time	t <sub>OFF</sub>	$R_L$ = 300 Ω, $C_L$ = 35 pF	Room Full		7	37 39	115
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	${ m C_L}$ = 1 nF, ${ m V_{GEN}}$ = 2 V, ${ m R_{GEN}}$ = 0 $\Omega$	Room		1		рС
Off-Isolation <sup>d</sup>	OIRR	$P = 50 \circ c = 5 \circ c f = 1 \text{ MHz}$	Room		- 78.5		
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 113		dB
Off-Isolation <sup>d</sup>	OIRR	$R_1 = 50 \Omega_1 C_1 = 5 pF_1 f = 10 MHz$	Room		- 58		uв
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$n_{L} = 50.52, O_{L} = 5.01, T = 10.0012$	Room		- 66		
011 0	C <sub>NO/NC(off)</sub>		Room		8		
Off Capacitance <sup>d</sup>	C <sub>COM(off)</sub>	$V_{IN} = 0$ or V+, f = 1 MHz	Room		14		pF
Channel On Canaditanaad	C <sub>NO/NC(on)</sub>	$v_{\rm IN} = 0.01 v_{\rm T}, 1 = 1.0012$	Room		27		p
Channel-On Capacitance <sup>d</sup>	C <sub>COM(on)</sub>		Room		27		
Power Supply							
Power Supply Current	l+	V <sub>IN</sub> = 0 or V+	Room Full		0.001	1.0 1.0	μΑ



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<b>SPECIFICATIONS</b> (V+	= 5 V)						
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 4.2 to 5.5 V, V_{IN} = 0.8 V or 2.0 V $^{e}$	Temp. <sup>a</sup>	Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	Unit
Analog Switch	•					•	
Analog Signal Range <sup>d</sup>	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		Full	0		V+	v
On-Resistance <sup>d</sup>	R <sub>ON</sub>		Room Full		2.6	3.5 3.7	
r <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	V+ = 4.2 V, V <sub>COM</sub> = 0.5/3.5 V I <sub>NO</sub> , I <sub>NC</sub> = 10 mA	Room		0.8	1.2	Ω
On-Resistance Match Between Channels <sup>d</sup>	$\Delta R_{DS(on)}$		Room			0.2	
Switch Off Leakage Current	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	V+ = 5.5 V, V <sub>NO</sub> , V <sub>NC</sub> = 1.0 V/4.5 V, V <sub>COM</sub> = 4.5 V/1.0 V	Room Full	- 2 - 20		2 20	nA
Switch On Leakage Current	I <sub>COM(off)</sub>		Room Full	- 2 - 20		2 20	
Channel-On Leakage Current	I <sub>COM(on)</sub>	V+ = 5.5 V, V <sub>NO</sub> , V <sub>NC</sub> = V <sub>COM</sub> = 1.0 V/4.5 V	Room Full	- 2 - 20		2 20	
Digital Control				-			
Input High Voltage <sup>d</sup>	V <sub>INH</sub>		Full	2.0			v
Input Low Voltage	V <sub>INL</sub>		Full			0.8	v
Input Capacitance	C <sub>in</sub>		Full		8		pF
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$	$V_{IN} = 0 \text{ or } V+$	Full	1		1	μA
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	V+ = 4.2 V, V <sub>NO</sub> or V <sub>NC</sub> = 3.0 V	Room Full		11	41 43	ns
Turn-Off Time	t <sub>OFF</sub>	$R_L = 300 \ \Omega, \ C_L = 35 \ pF$	Room Full		7	37 39	110
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	${\sf C}_{\sf L}$ = 1 nF, ${\sf V}_{\sf GEN}$ = 2 V, ${\sf R}_{\sf GEN}$ = 0 $\Omega$	Room		1		рС
Off Ormer items of	C <sub>NO/NC(off)</sub>	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		8		- 
Off Capacitance <sup>d</sup>	C <sub>COM(off)</sub>		Room		14		
	C <sub>NO/NC(on)</sub>		Room		28		pF
Channel-On Capacitance <sup>d</sup>	C <sub>COM(on)</sub>		Room		28		
Power Supply	1			r		1	
Power Supply Current	l+	V <sub>IN</sub> = 0 or V+	Room Full		0.001	1.0 1.0	μA

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

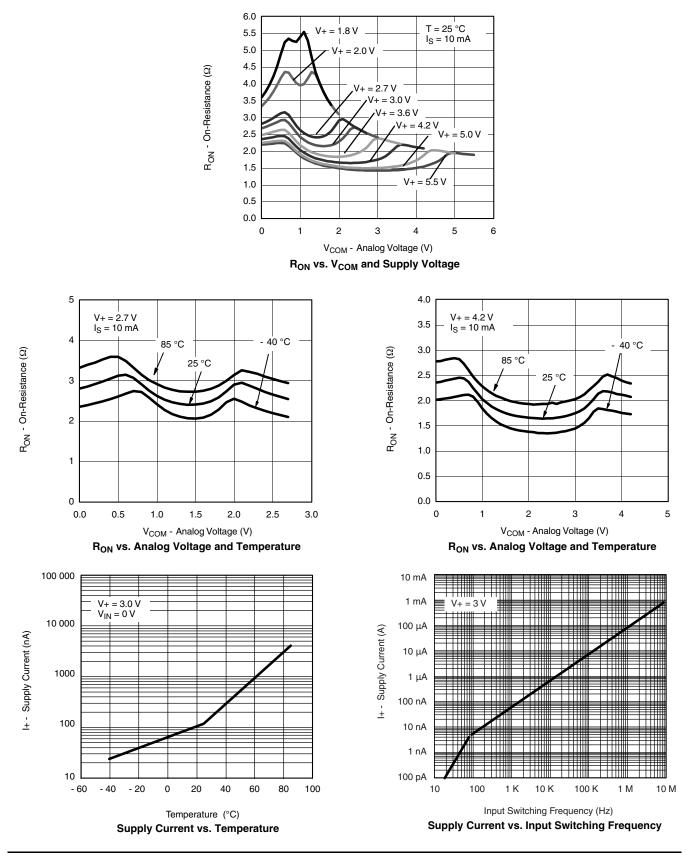
d. Guarantee by design, nor subjected to production test.

e. V<sub>IN</sub> = input voltage to perform proper function.

f. Guaranteed by 5 V leakage testing, not production tested.



### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

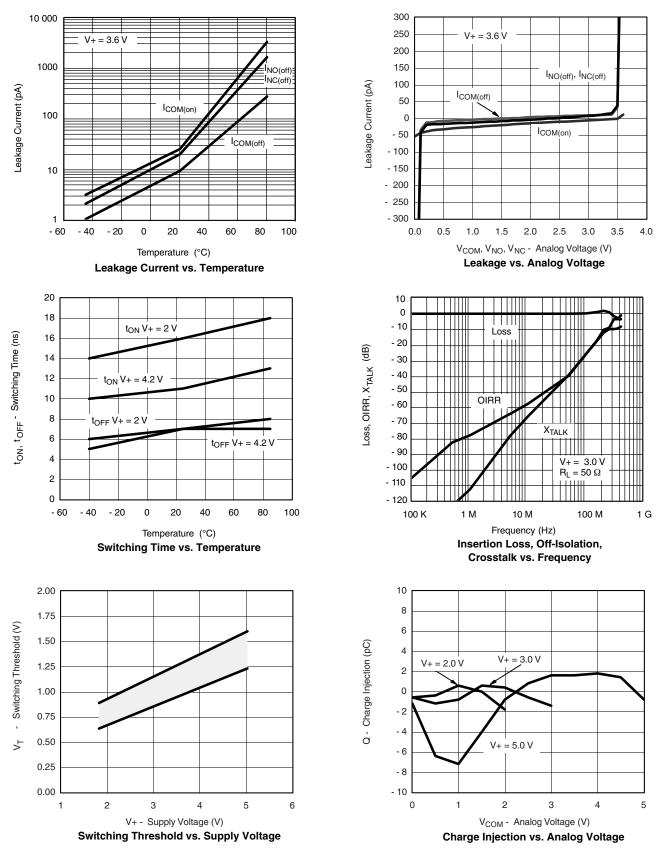


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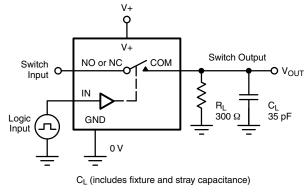
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



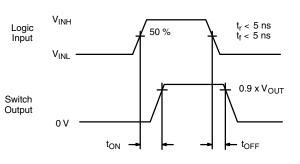
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## **TEST CIRCUITS**

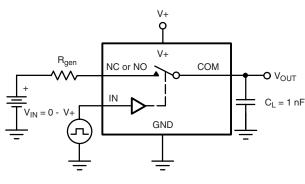


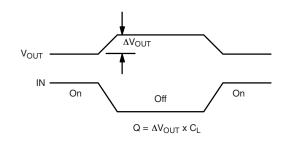




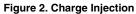
Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

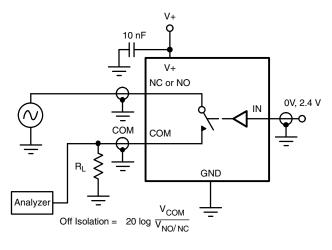






IN depends on switch configuration: input polarity determined by sense of switch.







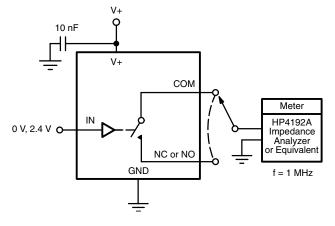


Figure 4. Channel Off/On Capacitance

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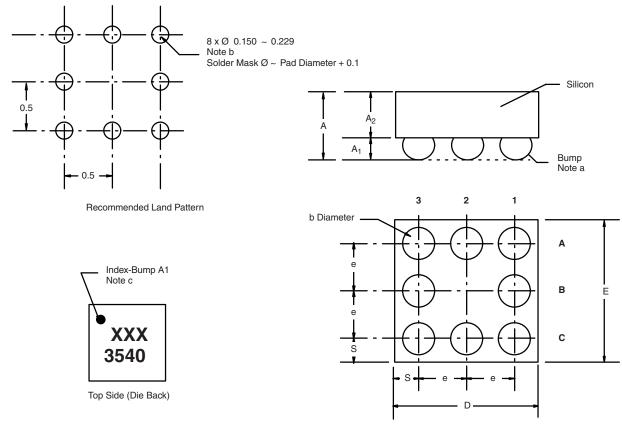




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### **PACKAGE OUTLINE**

### MICRO FOOT: 8 BUMP (3 x 3, 0.5 mm PITCH, 0.238 mm BUMP HEIGHT)



Notes (Unless Otherwise Specified):

a. Bump is Lead (Pb)-free Sn/Ag/Cu.

b. Non-solder mask defined copper landing pad.

c. Laser Mark on silicon die back; back-lapped, no coating. Shown is not actual marking; sample only.

	Millim	Millimeters <sup>a</sup>		hes
Dim.	Min.	Max.	Min.	Max.
Α	0.688	0.753	0.0271	0.0296
A <sub>1</sub>	0.218	0.258	0.0086	0.0102
A <sub>2</sub>	0.470	0.495	0.0185	0.0195
b	0.306	0.346	0.0120	0.0136
D	1.480	1.520	0.0583	0.0598
E	1.480	1.520	0.0583	0.0598
е	0.5 BASIC		0.0197	BASIC
S	0.230	0.270	0.0091	0.0106

Notes:

a. Use millimeters as the primary measurement.

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